

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









### Is Now Part of



## ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at <a href="https://www.onsemi.com">www.onsemi.com</a>

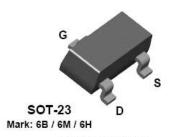
ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA Class 3 medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, emplo



February 2009

### 2N5484/5485/5486 MMBF5484/5485/5486





NOTE: Source & Drain are interchangeable

### **N-Channel RF Amplifier**

This device is designed primarily for electronic switching applications such as low On Resistance analog switching. Sourced from Process 50.

### Absolute Maximum Ratings\*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
$V_{DG}$	Drain-Gate Voltage	25	V	
V <sub>GS</sub>	Gate-Source Voltage	- 25	V	
I <sub>GF</sub>	Forward Gate Current	10	mA	
T <sub>J</sub> ,T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C	

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

<u>NOTES:</u>
1) These ratings are based on a maximum junction temperature of 150 degrees C.

#### **Thermal Characteristics** TA = 25°C unless otherwise noted

Symbol	Characteristic	Max		Units
		2N5484-5486	*MMBF5484-5486	
P <sub>D</sub>	Total Device Dissipation	350	225	mW
	Derate above 25°C	2.8	1.8	mW/°C
R <sub>e</sub> Jc	Thermal Resistance, Junction to Case	125		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	556	°C/W

<sup>\*</sup>Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

<sup>2)</sup> These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

# N-Channel RF Amplifier (continued)

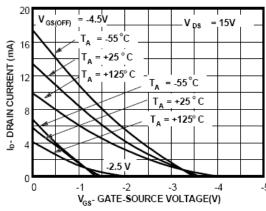
Cumbal	Parameter	Test Conditions	N1:	T	Mass	Units
Symbol	Parameter	rest Conditions	Min	Тур	Max	Units
OFF CHAI	RACTERISTICS					
V <sub>(BR)GSS</sub>	Gate-Source Breakdown Voltage	I <sub>G</sub> = - 1.0 μA, V <sub>DS</sub> = 0	- 25			V
I <sub>GSS</sub>	Gate Reverse Current	V <sub>GS</sub> = - 20 V, V <sub>DS</sub> = 0			- 1.0	nA
V <sub>GS(off)</sub>	Gate-Source Cutoff Voltage	V <sub>GS</sub> = - 20 V, V <sub>DS</sub> = 0, T <sub>A</sub> = 100°C V <sub>DS</sub> = 15 V, I <sub>D</sub> = 10 nA <b>5484</b>	- 0.3		- 0.2	μA
v G5(011)	outo-source outon voltage	5485	- 0.5		- 4.0	V
ON CHAR	ACTERISTICS	5486	- 2.0		- 6.0	V
I <sub>DSS</sub>	Zero-Gate Voltage Drain Current*	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0 <b>5484</b>	1.0		5.0	mA
-500		5485	4.0		10	mA
		5486	8.0		20	mA
SMALL SI	GNAL CHARACTERISTICS Forward Transfer Conductance	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0, f = 1.0 kHz	2000		0000	
		5484 5485	3000 3500		6000 7000	μmho μmho
		5486	4000		8000	μmho
Re(yis)	Input Conductance	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0, f = 100 MHz 5484			100	μmho
		V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0, f = 400 MHz <b>5485 / 5486</b>			1000	μmho
gos	Output Conductance	$V_{DS} = 15 \text{ V}, V_{GS} = 0, f = 1.0 \text{ kHz}$			50	
		5484 5485			60	μmho μmho
		5486			75	μmho
Re <sub>(yos)</sub>	Output Conductance	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0, f = 100 MHz <b>5484</b>			75	μmho
		V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0, f = 400 MHz <b>5485 / 5486</b>			100	μmho
Re(yfs)	Forward Transconductance	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0, f = 100 MHz			100	μππο
		<b>5484</b> V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0, f = 400 MHz	2500			μmho
		5485	3000			μmho
		5486	3500			μmho
Ciss	Input Capacitance	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0, f = 1.0 MHz			5.0	pF
Crss	Reverse Transfer Capacitance	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0, f = 1.0 MHz			1.0	pF
Coss	Output Capacitance	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0, f = 1.0 MHz			2.0	pF
NF	Noise Figure	$V_{DS}$ = 15 V, $R_{G}$ = 1.0 k $\Omega$ , f = 100 MHz 5484			3.0	dB
		$V_{DS}$ = 15 V, $R_{G}$ = 1.0 k $\Omega$ , f = 400 MHz 5484		4.0		dB
		$V_{DS}$ = 15 V , $R_{G}$ = 1.0 k $\Omega$ , f = 100 MHz 5485 / 5486			2.0	dB
		$V_{DS}$ = 15 V, $R_{G}$ = 1.0 kΩ, f = 400 MHz 5485 / 5486			4.0	dB

### N-Channel RF Amplifier

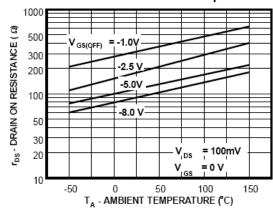
(continued)

### **Typical Characteristics**

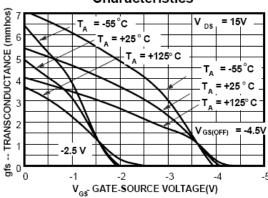




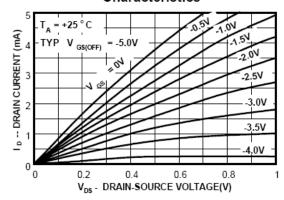
### **Channel Resistance vs Temperature**



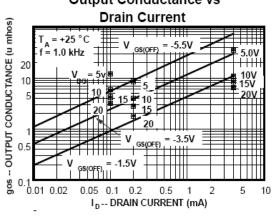
### Transconductance Characteristics



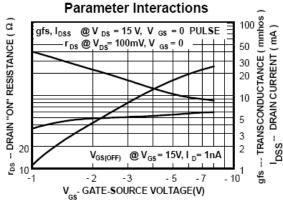
### Common Drain-Source Characteristics



#### **Output Conductance vs**

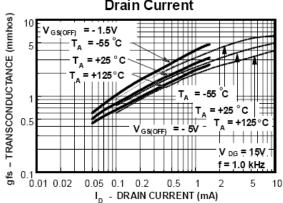


### Transconductance

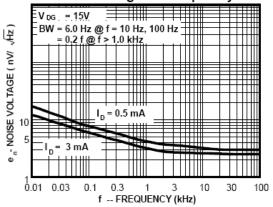


### Typical Characteristics (continued)

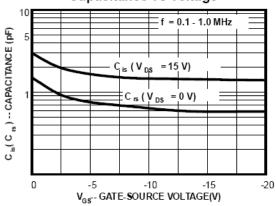
### Transconductance vs Drain Current



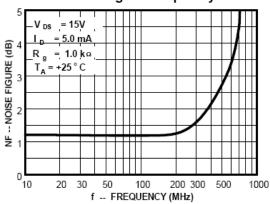
### Noise Voltage vs Frequency



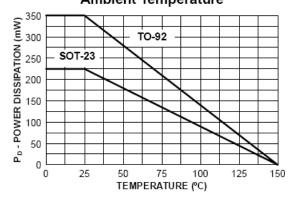
### Capacitance vs Voltage



### Noise Figure Frequency



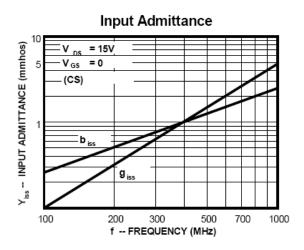
### Power Dissipation vs. Ambient Temperature

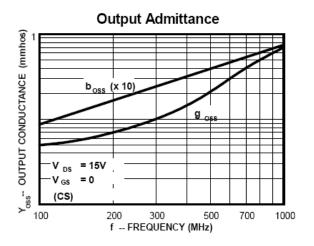


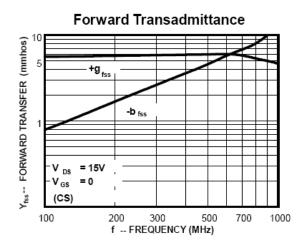
### N-Channel RF Amplifier

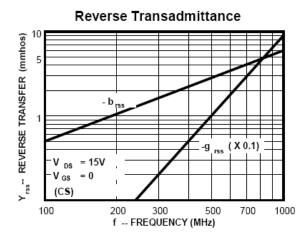
(continued)

#### **Common Source Characteristics**





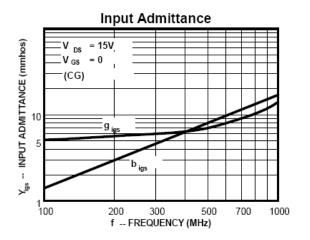


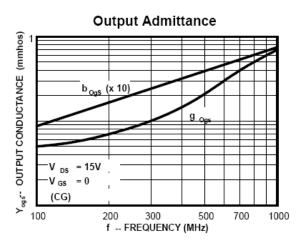


### **N-Channel RF Amplifier**

(continued)

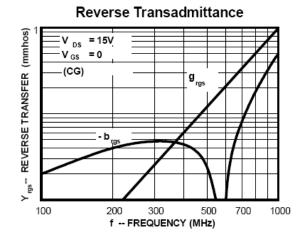
### **Common Gate Characteristics**





### 

f -- FREQUENCY (MHz)







#### **TRADEMARKS**

The following are registered and unregistered trademarks and service marks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

Power247® ACEx® Green FPS™ SuperSOT™-8 POWEREDGE® SyncFET™ Build it Now™ Green FPS™ e-Series™ The Power Franchise® CorePLUS™ GTO™ Power-SPM™ CROSSVOLT™ i-Lo<sup>TM</sup> PowerTrench® p wer CTL™ IntelliMAX™ Programmable Active Droop™ QFET® ISOPLANAR™ TinyBoost™ Current Transfer Logic™ EcoSPARK® MegaBuck™ QS<sup>TM</sup> TinyBuck™ TinyLogic<sup>®</sup> MICROCOUPLER™ QT Optoelectronics™ Fairchild<sup>®</sup> MicroFET™ Quiet Series™ TINYOPTO™ Fairchild Semiconductor® RapidConfigure™ TinyPower™ MicroPak™ TinyPWM™ FACT Quiet Series™ MillerDrive™ SMART START™ FACT<sup>®</sup> Motion-SPM™ SPM<sup>®</sup> TinyWire™  $\mathsf{FAST}^{\text{\tiny{\$}}}$ OPTOLOGIC® STEALTH™ μSerDes™ FastvCore™ OPTOPLANAR® UHC<sup>®</sup> SuperFET™ FPS™ UniFET™ SuperSOT™-3  $\mathsf{FRFET}^{\scriptscriptstyle{\textcircled{\tiny{\$}}}}$ PDP-SPM™ SuperSOT™-6 VCX™ Power220® Global Power Resource<sup>SM</sup>

#### **DISCLAIMER**

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

#### LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

#### As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.
- A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

### PRODUCT STATUS DEFINITIONS Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

Rev. I31

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <a href="https://www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor and severally, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and ho

#### **PUBLICATION ORDERING INFORMATION**

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81–3–5817–1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative